

BZX84C2V4ET1 Series

Zener Voltage Regulators

225 mW SOT-23 Surface Mount

This series of Zener diodes is offered in the convenient, surface mount plastic SOT-23 package. These devices are designed to provide voltage regulation with minimum space requirement. They are well suited for applications such as cellular phones, hand held portables, and high density PC boards.

Specification Features

- 225 mW Rating on FR-4 or FR-5 Board
- Zener Breakdown Voltage Range – 2.4 V to 75 V
- Package Designed for Optimal Automated Board Assembly
- Small Package Size for High Density Applications
- ESD Rating of Class 3 (>16 kV) per Human Body Model
- Peak Power – 225 W (8 X 20 μ s)
- Pb-Free Package is Available

Mechanical Characteristics

CASE: Void-free, transfer-molded, thermosetting plastic case

FINISH: Corrosion resistant finish, easily solderable

MAXIMUM CASE TEMPERATURE FOR SOLDERING PURPOSES:

260°C for 10 Seconds

POLARITY: Cathode indicated by polarity band

FLAMMABILITY RATING: UL 94 V-0

MAXIMUM RATINGS

| Rating | Symbol | Max | Unit |
|--|-----------------|----------------|-------------|
| Peak Power Dissipation @ 20 μ s (Note 1) @ $T_L \leq 25^\circ\text{C}$ | P_{pk} | 225 | Watts |
| Total Power Dissipation on FR-5 Board, (Note 2) @ $T_A = 25^\circ\text{C}$ Derated above 25°C | P_D | 225 1.8 | mW mW/°C |
| Thermal Resistance, Junction-to-Ambient | $R_{\theta JA}$ | 556 | °C/W |
| Total Power Dissipation on Alumina Substrate, (Note 3) @ $T_A = 25^\circ\text{C}$ Derated above 25°C | P_D | 300 2.4 | mW mW/°C |
| Thermal Resistance, Junction-to-Ambient | $R_{\theta JA}$ | 417 | °C/W |
| Junction and Storage Temperature Range | T_J, T_{stg} | -65 to +150 | °C |

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. Nonrepetitive current pulse per Figure 9.

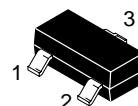
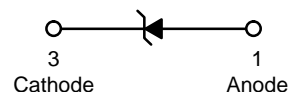
2. FR-5 = 1.0 X 0.75 X 0.62 in.

3. Alumina = 0.4 X 0.3 X 0.024 in, 99.5% alumina.



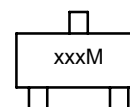
ON Semiconductor®

<http://onsemi.com>



SOT-23
CASE 318
STYLE 8

MARKING DIAGRAM



xxx = Specific Device Code

M = Date Code

ORDERING INFORMATION

| Device | Package | Shipping† |
|---------------|---------------------|--------------------|
| BZX84CxxxET1 | SOT-23 | 3000/Tape & Reel |
| BZX84CxxxET1G | SOT-23 (Pb-Free) | 3000/Tape & Reel |
| BZX84CxxxET3 | SOT-23 | 10,000/Tape & Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

DEVICE MARKING INFORMATION

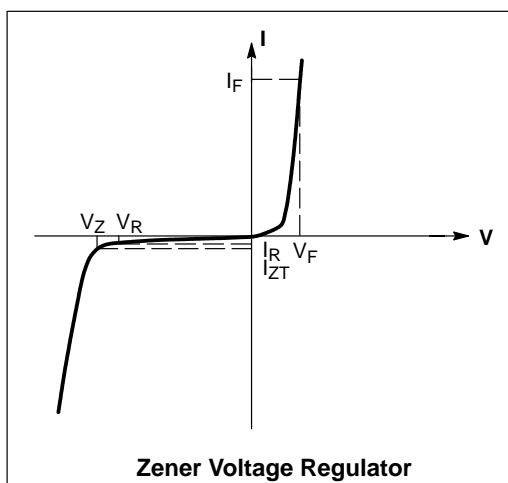
See specific marking information in the device marking column of the Electrical Characteristics table on page 2 of this data sheet.

BZX84C2V4ET1 Series

ELECTRICAL CHARACTERISTICS

(Pinout: 1-Anode, 2-No Connection, 3-Cathode) ($T_A = 25^\circ\text{C}$ unless otherwise noted, $V_F = 0.95\text{ V Max. @ } I_F = 10\text{ mA}$)

| Symbol | Parameter |
|---------------|---|
| V_Z | Reverse Zener Voltage @ I_{ZT} |
| I_{ZT} | Reverse Current |
| Z_{ZT} | Maximum Zener Impedance @ I_{ZT} |
| I_R | Reverse Leakage Current @ V_R |
| V_R | Reverse Voltage |
| I_F | Forward Current |
| V_F | Forward Voltage @ I_F |
| θ_{VZ} | Maximum Temperature Coefficient of V_Z |
| C | Max. Capacitance @ $V_R = 0$ and $f = 1\text{ MHz}$ |



ELECTRICAL CHARACTERISTICS

(Pinout: 1-Anode, 2-No Connection, 3-Cathode) ($T_A = 25^\circ\text{C}$ unless otherwise noted, $V_F = 0.90\text{ V Max. @ } I_F = 10\text{ mA}$)

(Devices listed in **bold, italic** are ON Semiconductor Preferred devices.)

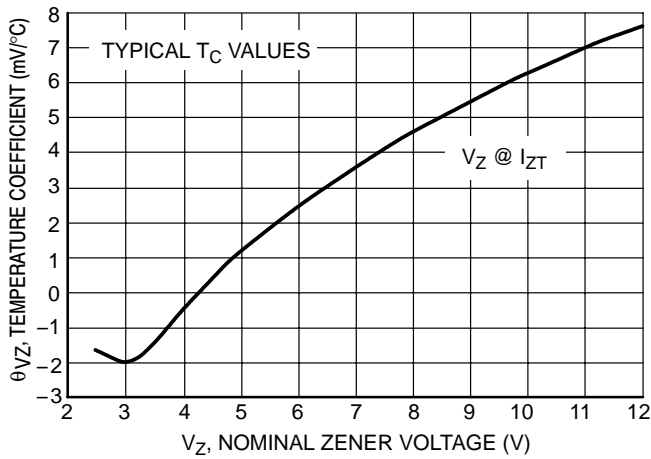
| Device | Device Marking | V_{Z1} (V) @ $I_{ZT1} = 5\text{ mA}$ (Note 4) | | | Z_{ZT1} (Ω) @ $I_{ZT1} = 5\text{ mA}$ | V_{Z2} (V) @ $I_{ZT2} = 1\text{ mA}$ (Note 4) | | Z_{ZT2} (Ω) @ $I_{ZT2} = 1\text{ mA}$ | V_{Z3} (V) @ $I_{ZT3} = 20\text{ mA}$ (Note 4) | | Z_{ZT3} (Ω) @ $I_{ZT3} = 20\text{ mA}$ | Max Reverse Leakage Current | | θ_{VZ} (mV/k) @ $I_{ZT1} = 5\text{ mA}$ | | C (pF) @ $V_R = 0$ $f = 1\text{ MHz}$ |
|-------------------------|----------------|---|------------|-------------|---|---|-------------|---|--|-------------|--|-----------------------------|-------------|---|-------------|---|
| | | Min | Nom | Max | | I_R (μA) | V_R (V) | | Min | Max | | | | | | |
| BZX84C3V3ET1 | BA4 | 3.1 | 3.3 | 3.5 | 95 | 2.3 | 2.9 | 600 | 3.6 | 4.2 | 40 | 5 | 1 | -3.5 | 0 | 450 |
| BZX84C4V7ET1 | BA9 | 4.4 | 4.7 | 5 | 80 | 3.7 | 4.7 | 500 | 4.5 | 5.4 | 15 | 3 | 2 | -3.5 | 0.2 | 260 |
| BZX84C5V1ET1 | BB1 | 4.8 | 5.1 | 5.4 | 60 | 4.2 | 5.3 | 480 | 5 | 5.9 | 15 | 2 | 2 | -2.7 | 1.2 | 225 |
| BZX84C5V6ET1 | BB2 | 5.2 | 5.6 | 6 | 40 | 4.8 | 6 | 400 | 5.2 | 6.3 | 10 | 1 | 2 | -2.0 | 2.5 | 200 |
| BZX84C6V2ET1, G* | BB3 | 5.8 | 6.2 | 6.6 | 10 | 5.6 | 6.6 | 150 | 5.8 | 6.8 | 6 | 3 | 4 | 0.4 | 3.7 | 185 |
| BZX84C6V8ET1 | BB4 | 6.4 | 6.8 | 7.2 | 15 | 6.3 | 7.2 | 80 | 6.4 | 7.4 | 6 | 2 | 4 | 1.2 | 4.5 | 155 |
| BZX84C7V5ET1 | BB5 | 7 | 7.5 | 7.9 | 15 | 6.9 | 7.9 | 80 | 7 | 8 | 6 | 1 | 5 | 2.5 | 5.3 | 140 |
| BZX84C10ET1 | BB8 | 9.4 | 10 | 10.6 | 20 | 9.3 | 10.6 | 150 | 9.4 | 10.7 | 10 | 0.2 | 7 | 4.5 | 8.0 | 130 |
| BZX84C12ET1 | BC1 | 11.4 | 12 | 12.7 | 25 | 11.2 | 12.7 | 150 | 11.4 | 12.9 | 10 | 0.1 | 8 | 6.0 | 10.0 | 130 |
| BZX84C15ET1 | BC3 | 14.3 | 15 | 15.8 | 30 | 13.7 | 15.5 | 200 | 13.9 | 15.7 | 20 | 0.05 | 10.5 | 9.2 | 13.0 | 110 |
| BZX84C16ET1 | BC4 | 15.3 | 16 | 17.1 | 40 | 15.2 | 17 | 200 | 15.4 | 17.2 | 20 | 0.05 | 11.2 | 10.4 | 14.0 | 105 |
| BZX84C18ET1 | BC5 | 16.8 | 18 | 19.1 | 45 | 16.7 | 19 | 225 | 16.9 | 19.2 | 20 | 0.05 | 12.6 | 12.4 | 16.0 | 100 |
| BZX84C24ET1 | BC8 | 22.8 | 24 | 25.6 | 70 | 22.7 | 25.5 | 250 | 22.9 | 25.7 | 25 | 0.05 | 16.8 | 18.4 | 22.0 | 80 |
| Device | Device Marking | V_{Z1} Below @ $I_{ZT1} = 2\text{ mA}$ | | | Z_{ZT1} Below @ $I_{ZT1} = 2\text{ mA}$ | V_{Z2} Below @ $I_{ZT2} = 0.1\text{ mA}$ | | Z_{ZT2} Below @ $I_{ZT2} = 0.5\text{ mA}$ | V_{Z3} Below @ $I_{ZT3} = 10\text{ mA}$ A | | Z_{ZT3} Below @ $I_{ZT3} = 10\text{ mA}$ | Max Reverse Leakage Current | | θ_{VZ} (mV/k) Below @ $I_{ZT1} = 2\text{ mA}$ | | C (pF) @ $V_R = 0$ $f = 1\text{ MHz}$ |
| | | Min | Nom | Max | | I_R (μA) | V_R (V) | | Min | Max | | | | | | |
| BZX84C27ET1 | BC9 | 25.1 | 27 | 28.9 | 80 | 25 | 28.9 | 300 | 25.2 | 29.3 | 45 | 0.05 | 18.9 | 21.4 | 25.3 | 70 |
| BZX84C43ET1 | BK6 | 40 | 43 | 46 | 150 | 39.7 | 46 | 375 | 40.1 | 46.5 | 80 | 0.05 | 30.1 | 37.6 | 46.6 | 40 |

* The "G" suffix indicates Pb-Free package available.

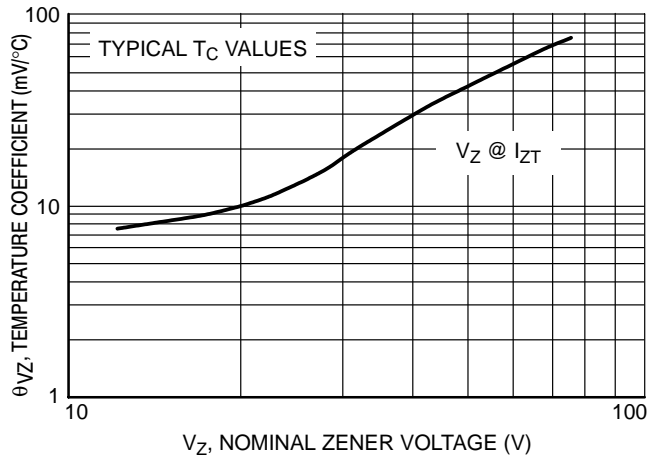
4. Zener voltage is measured with a pulse test current I_Z at an ambient temperature of 25°C

BZX84C2V4ET1 Series

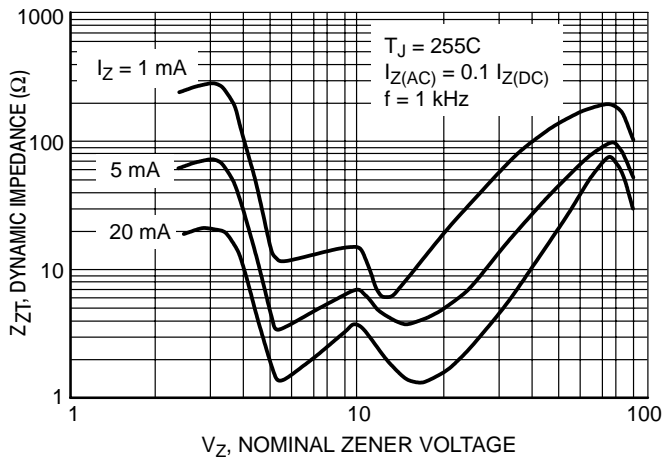
TYPICAL CHARACTERISTICS



**Figure 1. Temperature Coefficients
(Temperature Range -55°C to +150°C)**



**Figure 2. Temperature Coefficients
(Temperature Range -55°C to +150°C)**



**Figure 3. Effect of Zener Voltage on
Zener Impedance**

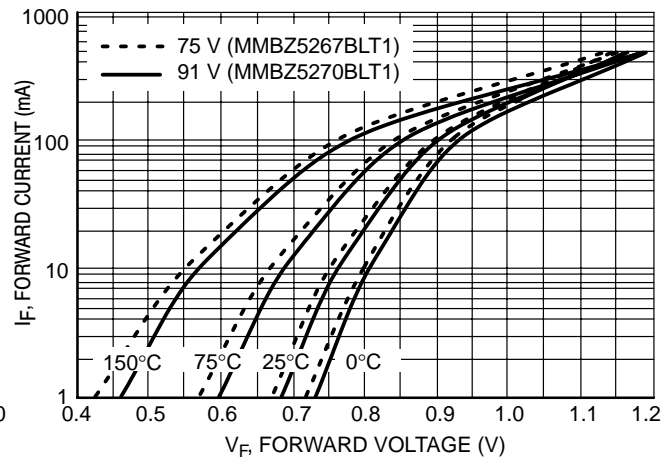


Figure 4. Typical Forward Voltage

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TYPICAL CHARACTERISTICS

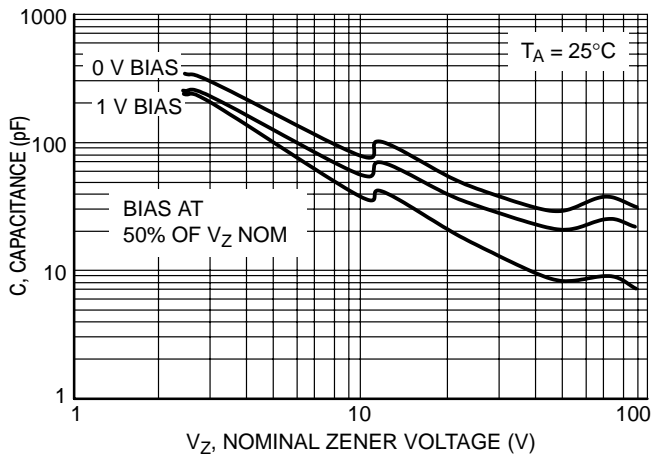


Figure 5. Typical Capacitance

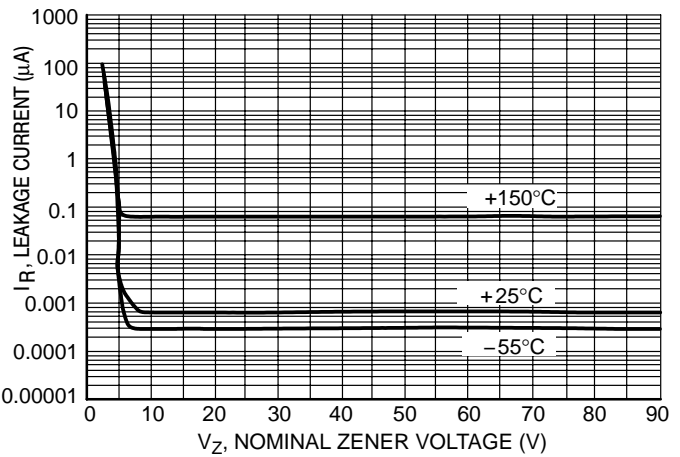


Figure 6. Typical Leakage Current

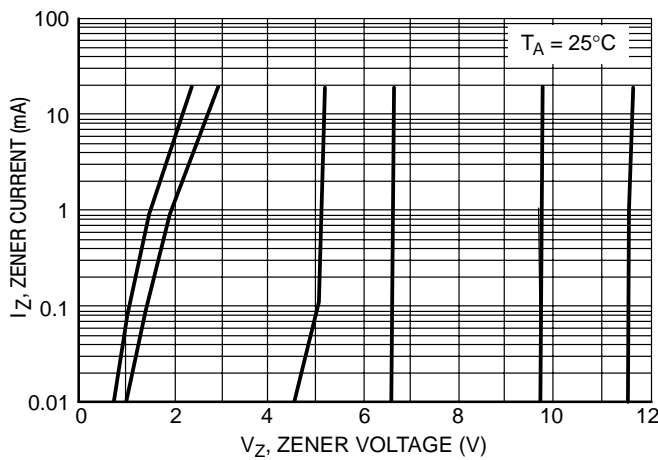


Figure 7. Zener Voltage versus Zener Current (V_Z Up to 12 V)

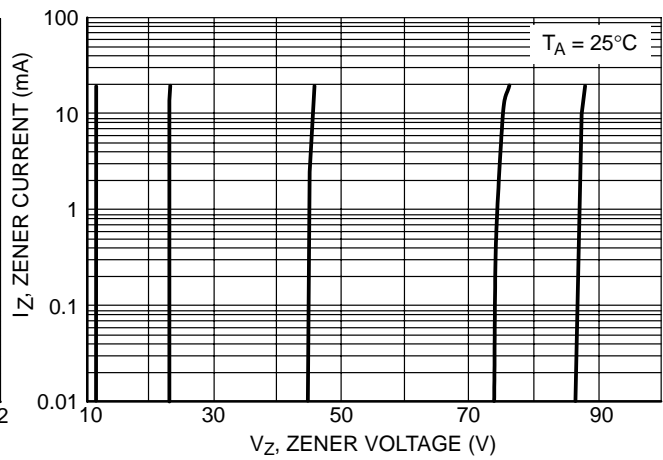


Figure 8. Zener Voltage versus Zener Current (12 V to 91 V)

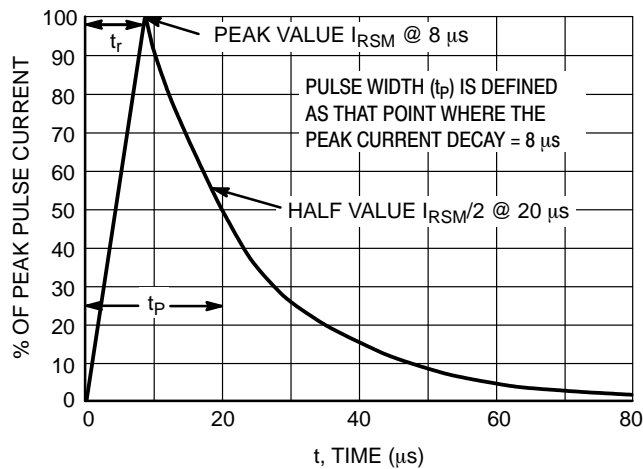
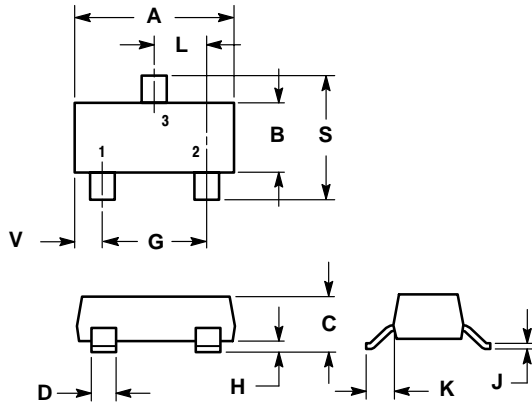


Figure 9. 8 × 20 μs Pulse Waveform

BZX84C2V4ET1 Series

PACKAGE DIMENSIONS

SOT-23
TO-236AB
CASE 318-09
ISSUE AJ



NOTES:

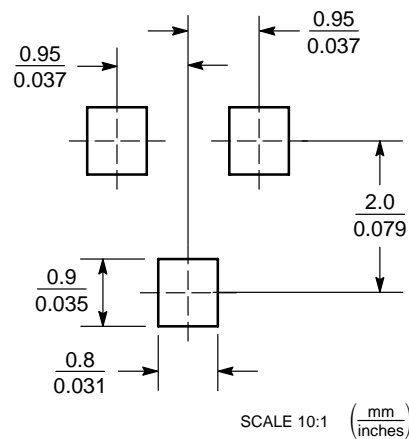
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. 318-01, -02, AND -06 OBSOLETE, NEW STANDARD 318-09.

| DIM | INCHES | | MILLIMETERS | |
|-----|--------|--------|-------------|-------|
| | MIN | MAX | MIN | MAX |
| A | 0.1102 | 0.1197 | 2.80 | 3.04 |
| B | 0.0472 | 0.0551 | 1.20 | 1.40 |
| C | 0.0385 | 0.0498 | 0.99 | 1.26 |
| D | 0.0140 | 0.0200 | 0.36 | 0.50 |
| G | 0.0670 | 0.0826 | 1.70 | 2.10 |
| H | 0.0040 | 0.0098 | 0.10 | 0.25 |
| J | 0.0034 | 0.0070 | 0.085 | 0.177 |
| K | 0.0180 | 0.0236 | 0.45 | 0.60 |
| L | 0.0350 | 0.0401 | 0.89 | 1.02 |
| S | 0.0830 | 0.0984 | 2.10 | 2.50 |
| V | 0.0177 | 0.0236 | 0.45 | 0.60 |

STYLE 8:

1. ANODE
2. NO CONNECTION
3. CATHODE

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

BZX84C2V4ET1 Series

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